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Patent

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert Falster, et al.
Serial No. 10/685,251
Filed October 14, 2003
For LOW DEFECT DENSITY, SELF-INTERSTITIAL DOMINATED SILICON

November 26, 2003

PRELIMINARY AMENDMENT A PRIOR TO EXAMINATION

TO THE COMMISSIONER OF PATENTS AND TRADEMARKS,

SIR:

Please enter the following amendments prior to examination of the above-referenced patent application:

Amendments to the Specification are reflected in the listing of claims that begins on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims that begins on page 3 of this paper.

Remarks begin on page 7 of this paper.